

**5 Amp 100 Volt High Voltage Schottky
Barrier Rectifier**
DESCRIPTION

The UPDS5100H offers a small and powerful surface mount package for a 100 Volt 5 Amp rated Schottky with low forward voltage and very low leakage current. For critical applications requiring very fast switching, these Schottky higher reverse voltage ratings with their "hot carrier" features provide extremely fast switching to replace conventional ultrafast rectifiers. The very low thermal resistance of the PowerDI™5 package design permits cooler operating junction temperatures for minimal reverse leakage currents and lower power loss.

APPEARANCE

PowerDI™5

IMPORTANT: For the most current data, consult MICROSEMI's website: <http://www.microsemi.com>

FEATURES

- Guard Ring Die Construction for Transient Protection
- High Current Low Forward Voltage Drop
- Very Low Leakage Current
- High Junction Temperature Capability
- High Forward Surge Current Capability
- "Green" Molding Compound (No Br, Sb)
- Low inductive parasitics for minimal Ldi/dt effects
- Lead-Free Finish & RoHS Compliant per EU Directive Rev 13.2.2003 (Glass and High Temperature Solder Exemptions Applied per Annex Notes 5 and 7)

APPLICATIONS / BENEFITS

- Silicon Schottky (hot carrier) rectifier for minimal t_{rr} and elimination of reverse-recovery oscillations to reduce need for EMI filtering
- For use in high-frequency switching power supplies, inverters, free wheeling, and polarity protection applications
- Low power loss and high efficiency
- Robust package configuration for pick-and-place handling
- Full-metallic bottom eliminates flux entrapment

MAXIMUM RATINGS

- Junction and Storage Temperature (T_J , T_{STG}): -65 to +150°C
- Average Rectified Output Current (I_O): 5 Amps for Single phase, half wave, 60Hz, resistive or inductive load (also see Figure 5). For capacitive load, derate current by 20%.
- Peak Repetitive Reverse Voltage (V_{RRM}): 100 V
Working Peak Reverse Voltage (V_{RWM}): 100 V
DC Blocking Voltage (V_R): 100 V
- RMS Reverse Voltage ($V_{R(RMS)}$): 71 V
- Non-Repetitive Peak Forward Surge Current @ 8.3 ms Single half sine-wave Superimposed on Rated Load (I_{FSM}): 250A
- Thermal Resistance Junction to case bottom ($R_{\theta JC}$) or Soldering Point ($R_{\theta JS}$): 2.0°C/W
- Thermal Resistance ($R_{\theta JA}$): 110°C/W junction to ambient when mounted on FR-4 PCB, 2 oz. Copper and minimum recommended pad layout (see last page)

MECHANICAL AND PACKAGING

- Case Material: Molded Plastic, Environmentally Friendly "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020C.
- Terminals: Finish – Matte Tin annealed over Copper lead frame (**e3** per JESD97) Solderable per MIL-STD-202, Method 208
- Marking: See marking information on page 3
- Polarity: See Diagram
- Weight: 0.096 grams (approx.)
- Tape & Reel Option: 5000/reel (13")

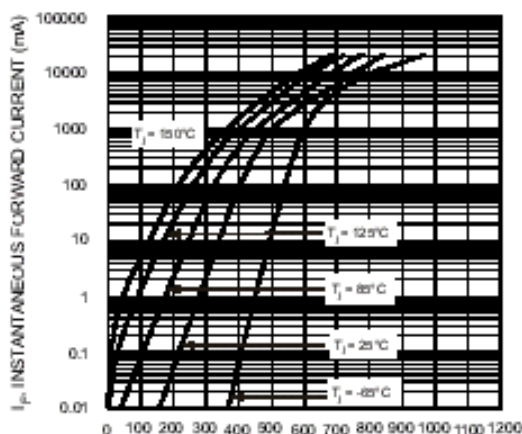
ELECTRICAL CHARACTERISTICS @ 25°C unless specified otherwise

	Working Peak Reverse Voltage	Maximum RMS Voltage	Minimum Reverse Breakdown Voltage	Maximum Forward Voltage (Note 2)		Maximum Reverse Current I_R @ V_{RWM} (Note 1)	Maximum Reverse Current I_R @ V_{RWM} , 125°C (Note 1)
Part Number	V_{RWM} Volts	V_{RMS} Volts	V_{BR} Volts	V_F @ 5A Volts	V_F @ 10A Volts	I_R μA	I_R mA
UPDS5100H	100	71	100	0.71	0.80	10	4.5

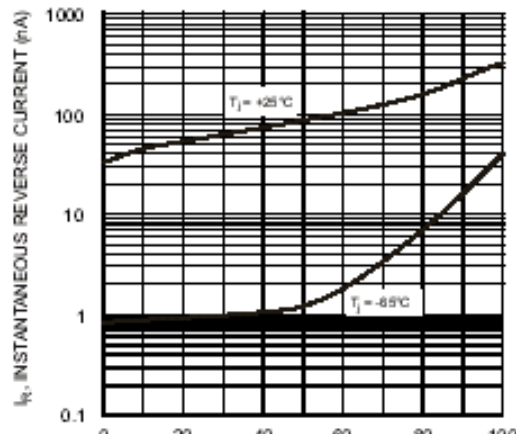
NOTE 1: Short duration test pulse used to minimize self-heating effect.

NOTE 2: See Figure 1 for typical values at various temperatures

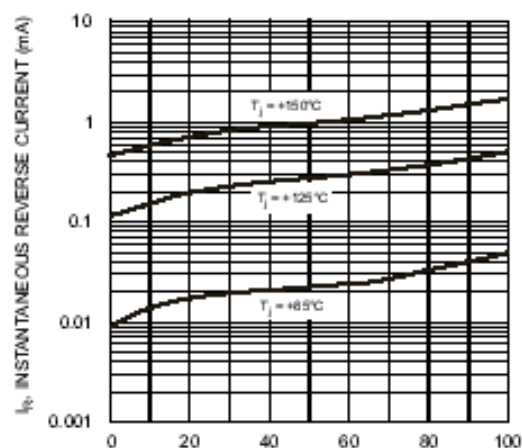
GRAPHS



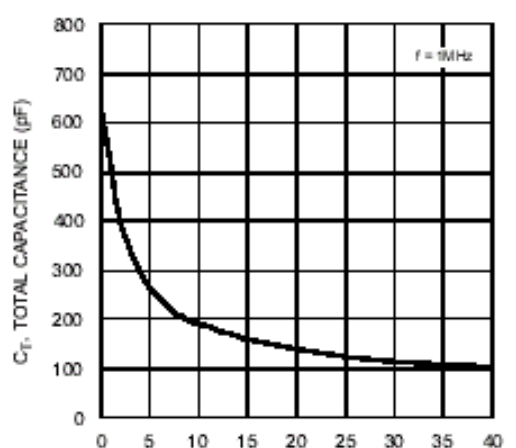
V_F , INSTANTANEOUS FORWARD VOLTAGE (mV)
Fig. 1 Typical Forward Characteristics



V_R , INSTANTANEOUS REVERSE VOLTAGE (V)
Fig. 2 Typical Reverse Characteristics



V_R , INSTANTANEOUS REVERSE VOLTAGE (V)
Fig. 3 Typical Reverse Characteristics



V_R , REVERSE VOLTAGE (V)
Fig. 4 Typical Total Capacitance vs. Reverse Voltage

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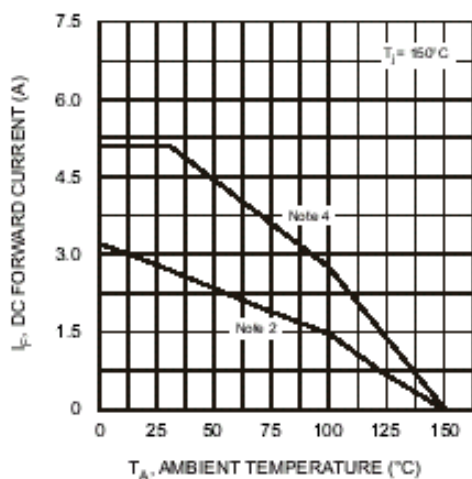


Fig. 5 DC Forward Current Derating

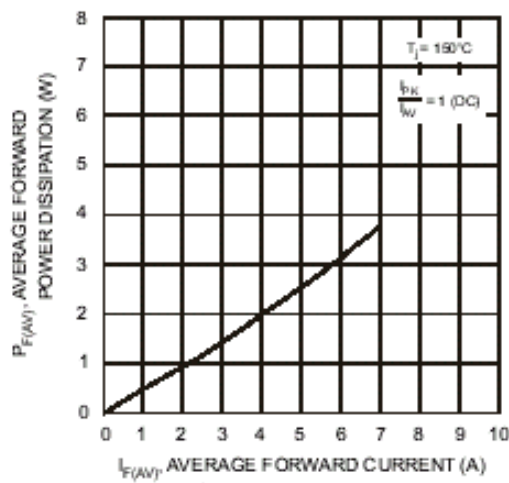


Fig. 6 Forward Power Dissipation

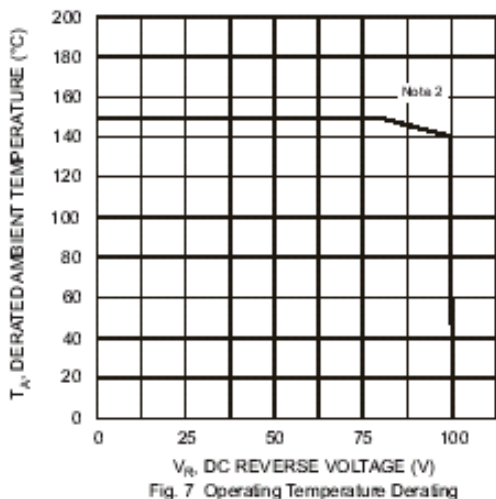


Fig. 7 Operating Temperature Derating

NOTE 2: FR-4 PCB, 2 oz. Copper, minimum recommended pad layout.

NOTE 3: Short duration test pulse used to minimize self-heating effects.

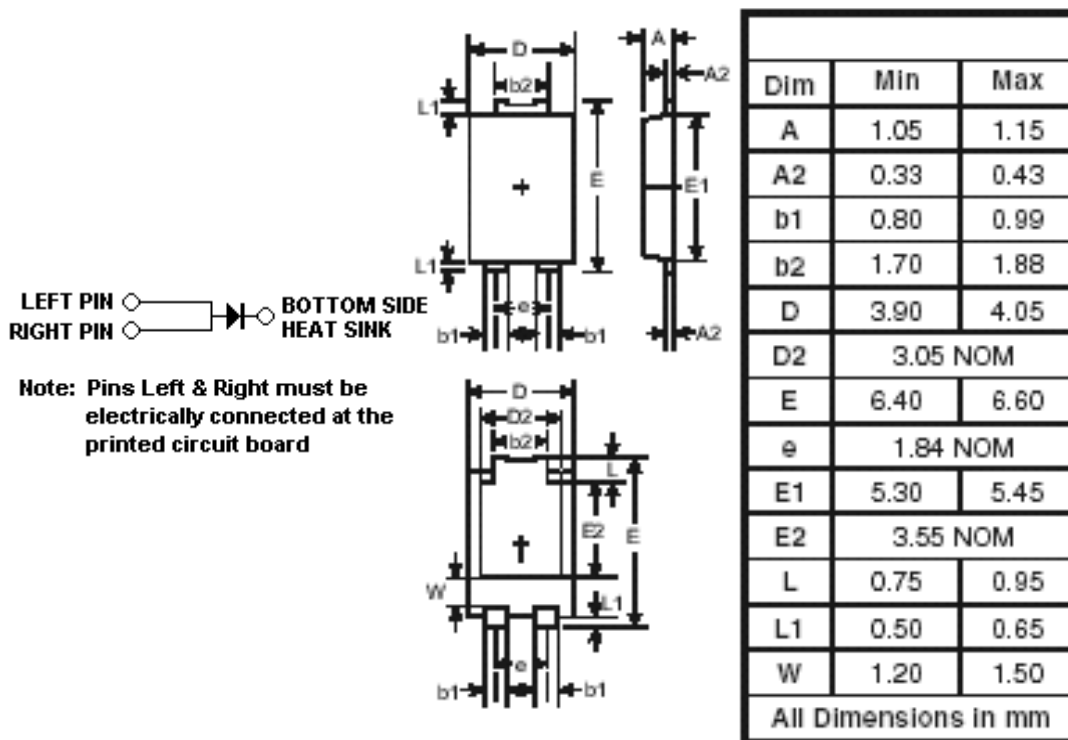
NOTE 4: Polyimide PCB, 2 oz. Copper. Cathode pad dimensions 9.4mm x 7.2mm. Anode pad dimensions 2.7mm x 1.6mm.

MARKING INFORMATION



S5100H = Product type marking code.
MSC = Manufacturers' code marking
YYWW = Date code marking
YY = Last digit of year ex: 04 for 2004
WW = Week code 01 to 52

DIMENSIONS AND SCHEMATIC



PowerDI™5

MOUNTING PAD DIMENSIONS

PAD dimensions (mm)	
Z	6.6
X1	1.4
X2	3.6
Y1	0.8
Y2	4.7
C	3.87
E1	0.9

